



BFT25A

NPN 5 GHz wideband transistor

Rev. 5 — 12 September 2011

Product data sheet

1. Product profile

1.1 General description

The BFT25A is a silicon NPN transistor, primarily intended for use in RF low power amplifiers, such as pocket telephones and paging systems with signal frequencies up to 2 GHz.

The transistor is encapsulated in a 3-pin plastic SOT23 envelope.

1.2 Features and benefits

- Low current consumption (100 μ A to 1 mA)
- Low noise figure
- Gold metallization ensures excellent reliability.

1.3 Quick reference data

Table 1. Quick reference data

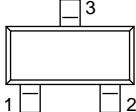
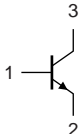
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	-	8	V
V_{CEO}	collector-emitter voltage	open base	-	-	5	V
I_C	DC collector current		-	-	6.5	mA
P_{tot}	total power dissipation	up to $T_s = 165\text{ }^\circ\text{C}$	[1]	-	32	mW
h_{FE}	DC current gain	$I_C = 0.5\text{ mA}; V_{CE} = 1\text{ V}$	50	80	200	
f_T	transition frequency	$I_C = 1\text{ mA}; V_{CE} = 1\text{ V};$ $T_{amb} = 25\text{ }^\circ\text{C};$ $f = 500\text{ MHz}$	3.5	5	-	GHz
G_{UM}	maximum unilateral power gain	$I_C = 0.5\text{ mA}; V_{CE} = 1\text{ V};$ $T_{amb} = 25\text{ }^\circ\text{C};$ $f = 1\text{ GHz}$	-	15	-	dB
F	noise figure	$\Gamma = \Gamma_{opt}; I_C = 0.5\text{ mA};$ $V_{CE} = 1\text{ V};$ $T_{amb} = 25\text{ }^\circ\text{C}; f = 1\text{ GHz}$	-	1.8	-	dB
		$\Gamma = \Gamma_{opt}; I_C = 1\text{ mA};$ $V_{CE} = 1\text{ V};$ $T_{amb} = 25\text{ }^\circ\text{C}; f = 1\text{ GHz}$	-	2	-	dB

[1] T_s is the temperature at the soldering point of the collector tab.



2. Pinning information

Table 2. Discrete pinning

Pin	Description	Simplified outline	Symbol
Code: V10			
1	base		
2	emitter		
3	collector		

sym021

3. Ordering information

Table 3. Ordering information

Type number	Package		Version
	Name	Description	
BFT25A	-	plastic surface mounted package; 3 leads	SOT23

4. Marking

Table 4. Marking

Type number	Marking code ^[1]
BFT25A	34*

- [1] * = p : Made in Hong Kong.
 * = t : Made in Malaysia.
 * = W : Made in China.

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	8	V
V_{CEO}	collector-emitter voltage	open base	-	5	V
V_{EBO}	emitter-base voltage	open collector	-	2	V
I_C	DC collector current		-	6.5	mA
P_{tot}	total power dissipation	up to $T_s = 165\text{ °C}$ ^[1]	-	32	mW
T_{stg}	storage temperature		-65	+150	°C
T_j	junction temperature		-	175	°C

- [1] T_s is the temperature at the soldering point of the collector tab.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-s)}$	from junction to soldering point		[1] 260	K/W

[1] T_s is the temperature at the soldering point of the collector tab.

7. Characteristics

Table 7. Characteristics

$T_j = 25\text{ °C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CBO}	collector cut-off current	$I_E = 0\text{ A}; V_{CB} = 5\text{ V}$	-	-	50	nA
h_{FE}	DC current gain	$I_C = 0.5\text{ mA}; V_{CE} = 1\text{ V}$	50	80	200	
f_T	transition frequency	$I_C = 1\text{ mA}; V_{CE} = 1\text{ V};$ $T_{amb} = 25\text{ °C};$ $f = 500\text{ MHz}$	3.5	5	-	GHz
C_{re}	feedback capacitance	$I_C = I_c = 0\text{ A}; V_{CB} = 1\text{ V};$ $f = 1\text{ MHz}$	-	0.3	0.45	pF
G_{UM}	maximum unilateral power gain	$I_C = 0.5\text{ mA}; V_{CE} = 1\text{ V};$ $T_{amb} = 25\text{ °C}; f = 1\text{ GHz}$	[1] -	15	-	dB
F	noise figure	$\Gamma = \Gamma_{opt}; I_C = 0.5\text{ mA};$ $V_{CE} = 1\text{ V};$ $T_{amb} = 25\text{ °C}; f = 1\text{ GHz}$	-	1.8	-	dB
		$\Gamma = \Gamma_{opt}; I_C = 1\text{ mA};$ $V_{CE} = 1\text{ V};$ $T_{amb} = 25\text{ °C}; f = 1\text{ GHz}$	-	2	-	dB

[1] G_{UM} is the maximum unilateral power gain, assuming S_{12} is zero and

$$G_{UM} = 10 \log \frac{|S_{21}|^2}{(1 - |S_{11}|^2)(1 - |S_{22}|^2)} \text{ dB}$$

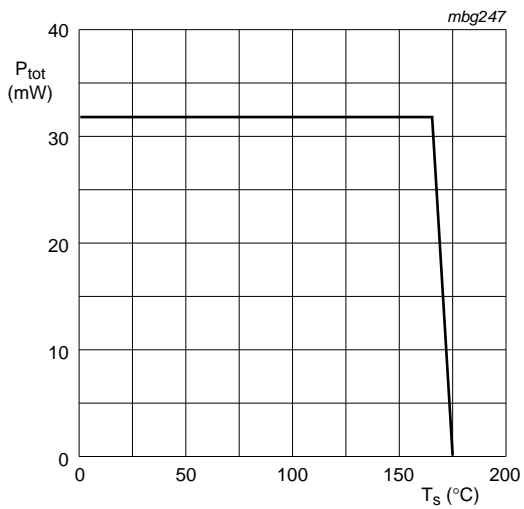
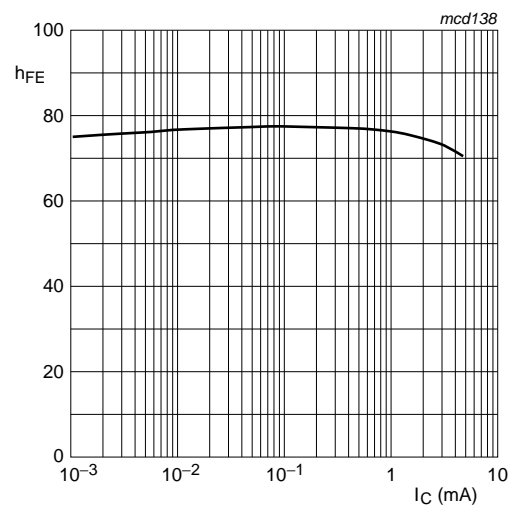
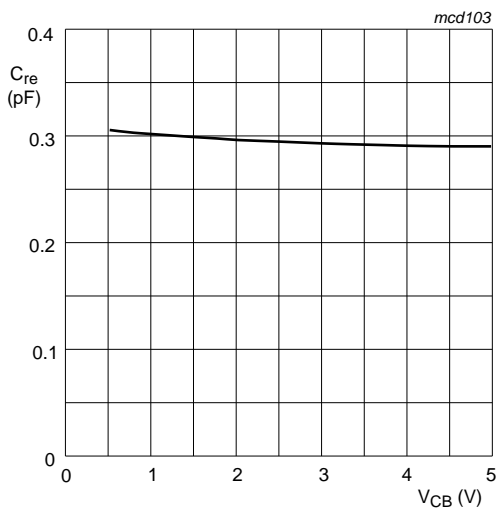


Fig 1. Power derating curve.



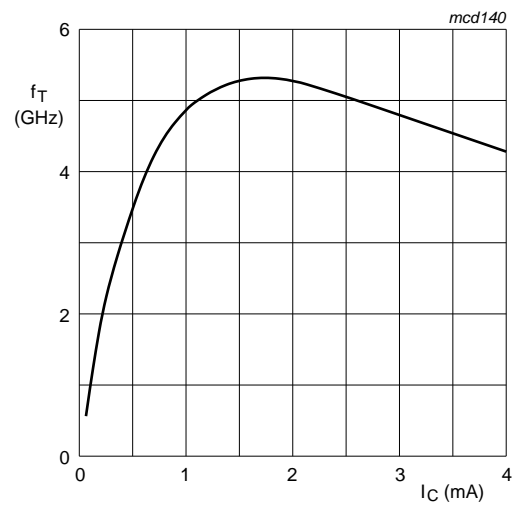
$V_{CE} = 1$ V.

Fig 2. DC current gain as a function of collector current.



$I_C = i_c = 0$ A; $f = 1$ MHz.

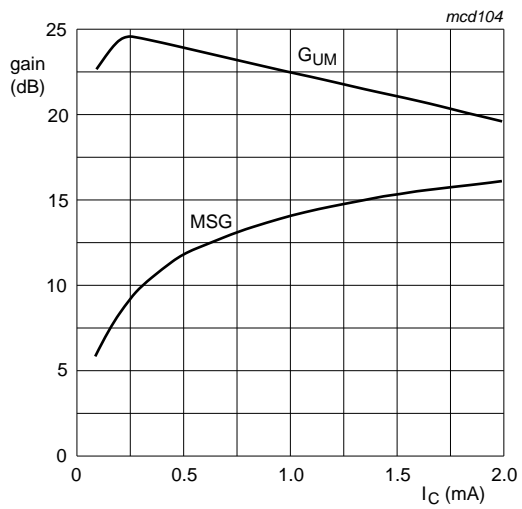
Fig 3. Feedback capacitance as a function of collector-base voltage.



$V_{CE} = 1$ V; $T_{amb} = 25$ °C; $f = 500$ MHz.

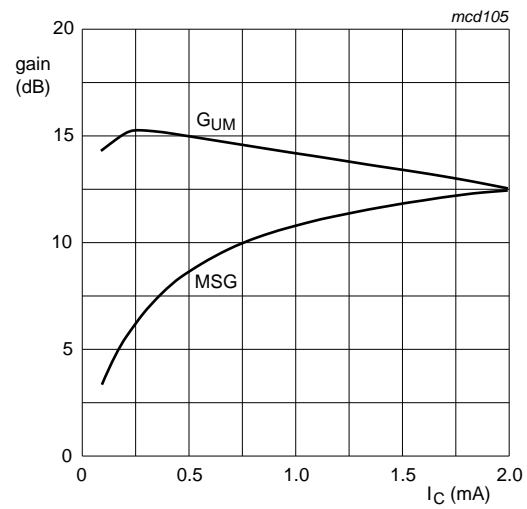
Fig 4. Transition frequency as a function of collector current.

Figure 5, 6, 7 and 8, G_{UM} = maximum unilateral power gain; MSG = maximum stable gain.



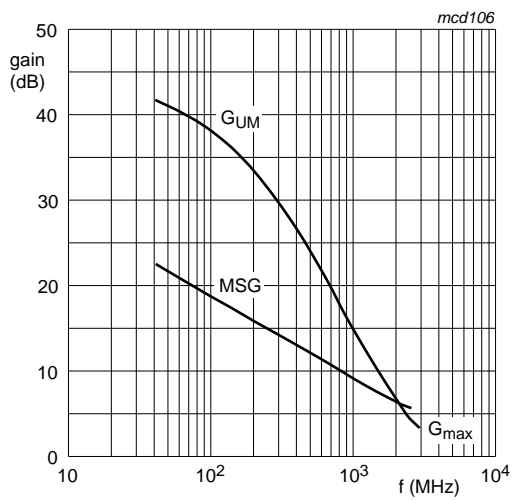
$V_{CE} = 1\text{ V}; f = 500\text{ MHz}$.

Fig. 5. Gain as a function of collector current.



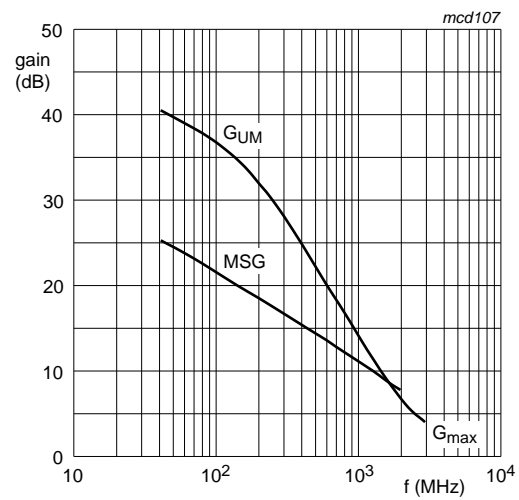
$V_{CE} = 1\text{ V}; f = 1\text{ GHz}$.

Fig. 6. Gain as a function of collector current.



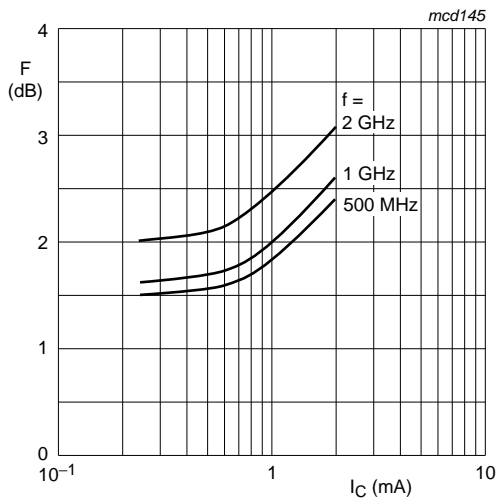
$V_{CE} = 1\text{ V}; I_C = 0.5\text{ mA}$.

Fig. 7. Gain as a function of frequency.



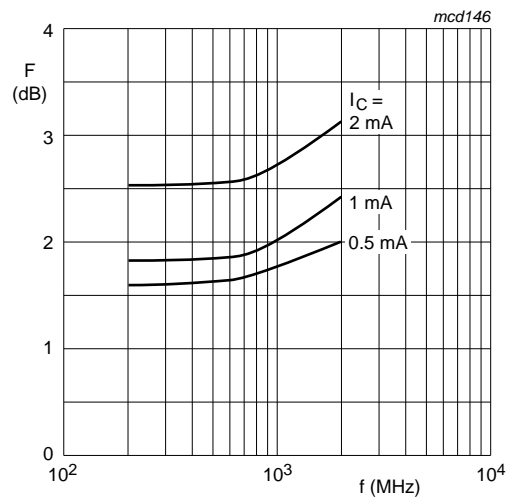
$V_{CE} = 1\text{ V}; I_C = 1\text{ mA}$.

Fig. 8. Gain as a function of frequency.



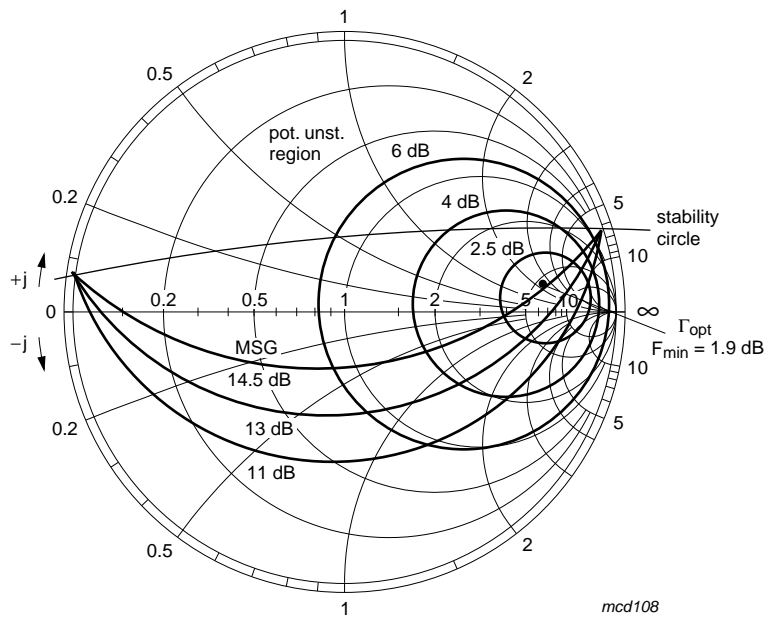
$V_{CE} = 1\text{ V.}$

Fig 9. Minimum noise figure as a function of collector current.



$V_{CE} = 1\text{ V.}$

Fig 10. Minimum noise figure as a function of frequency.



See [Table 8](#);
 $Z_o = 50\ \Omega$.
 Average gain parameter: $MSG = 14.5\text{ dB.}$

Fig 11. Noise circle figure.

Table 8. Noise parameters

f (MHz)	V _{CE} (V)	I _C (mA)	F _{min} (dB)	Γ _{opt}		R _n /50
				(mag)	(ang)	
500	1	1	1.9	0.79	4	2.5

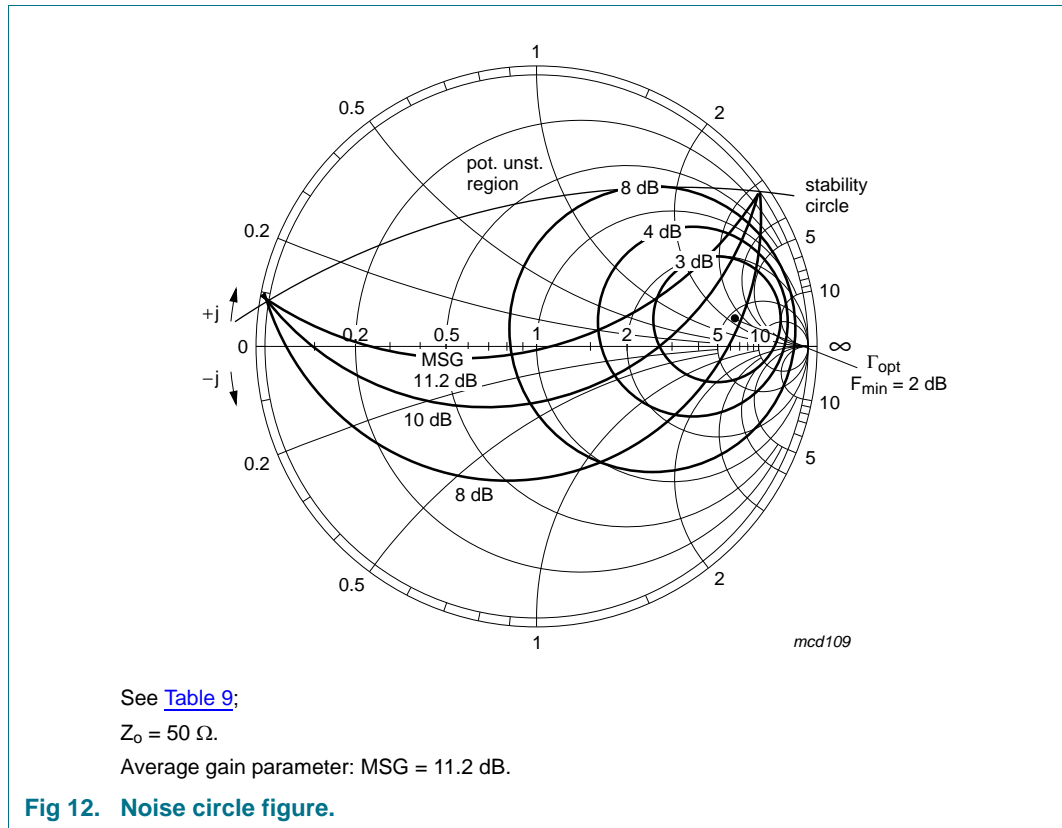


Table 9. Noise parameters

f (MHz)	V _{CE} (V)	I _C (mA)	F _{min} (dB)	Γ _{opt}		R _n /50
				(mag)	(ang)	
1000	1	1	2	0.74	8	2.6

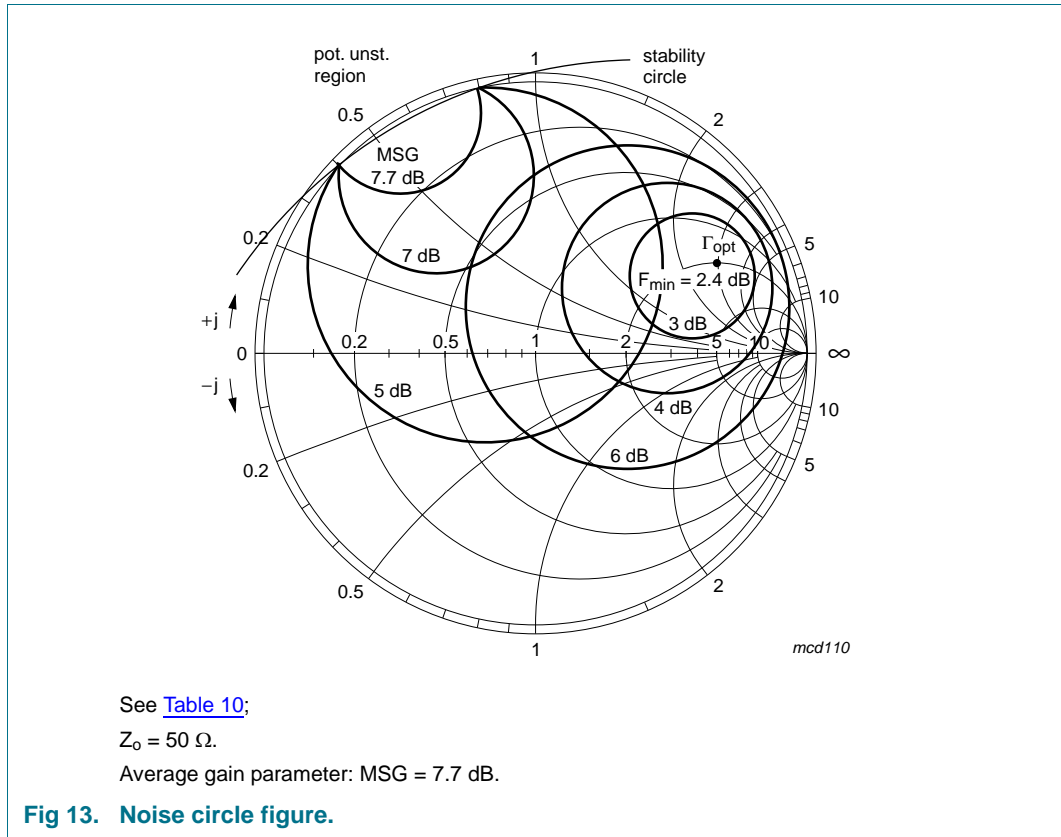
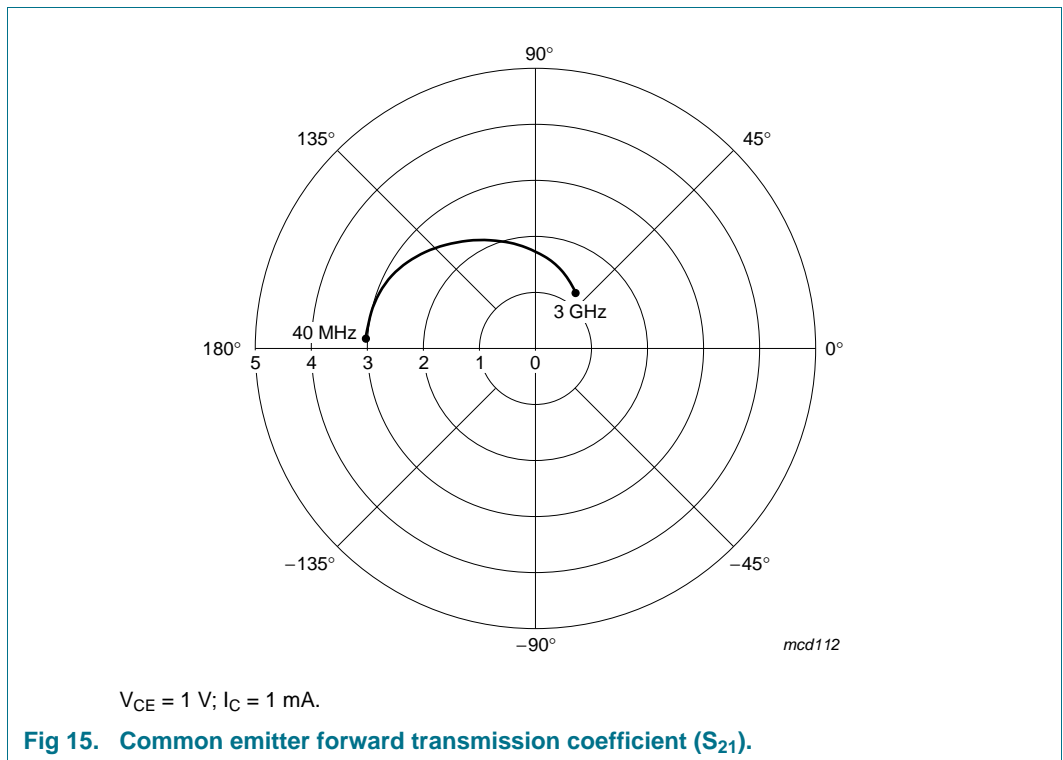
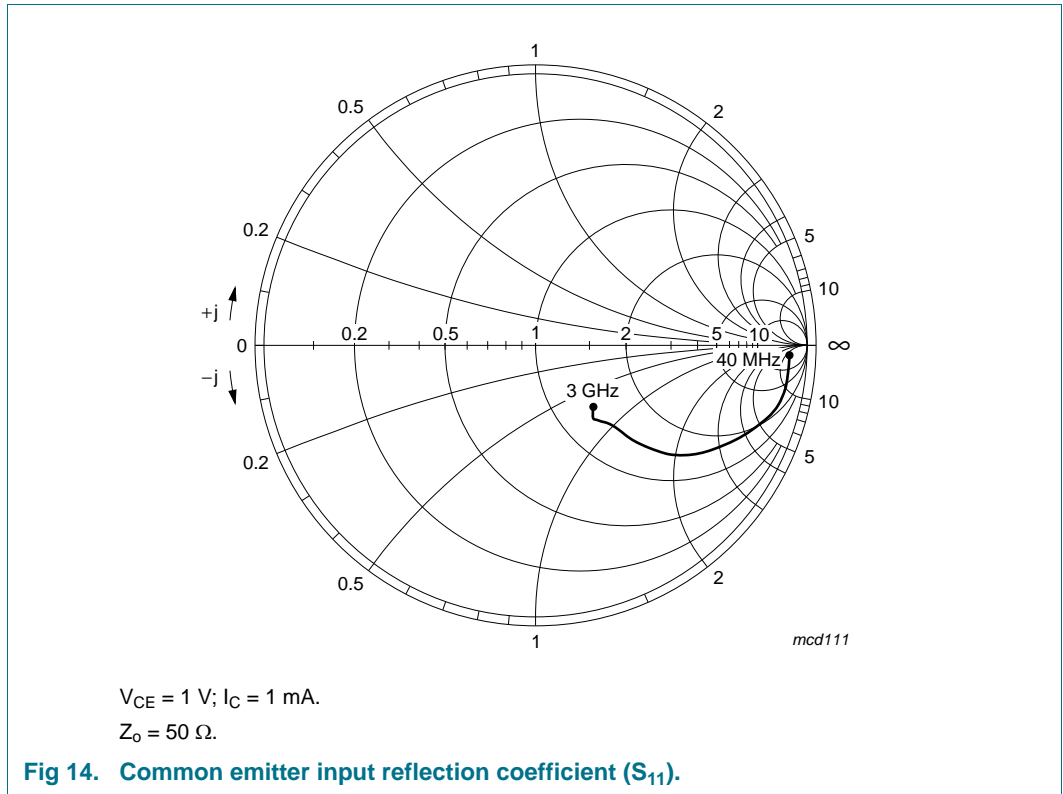
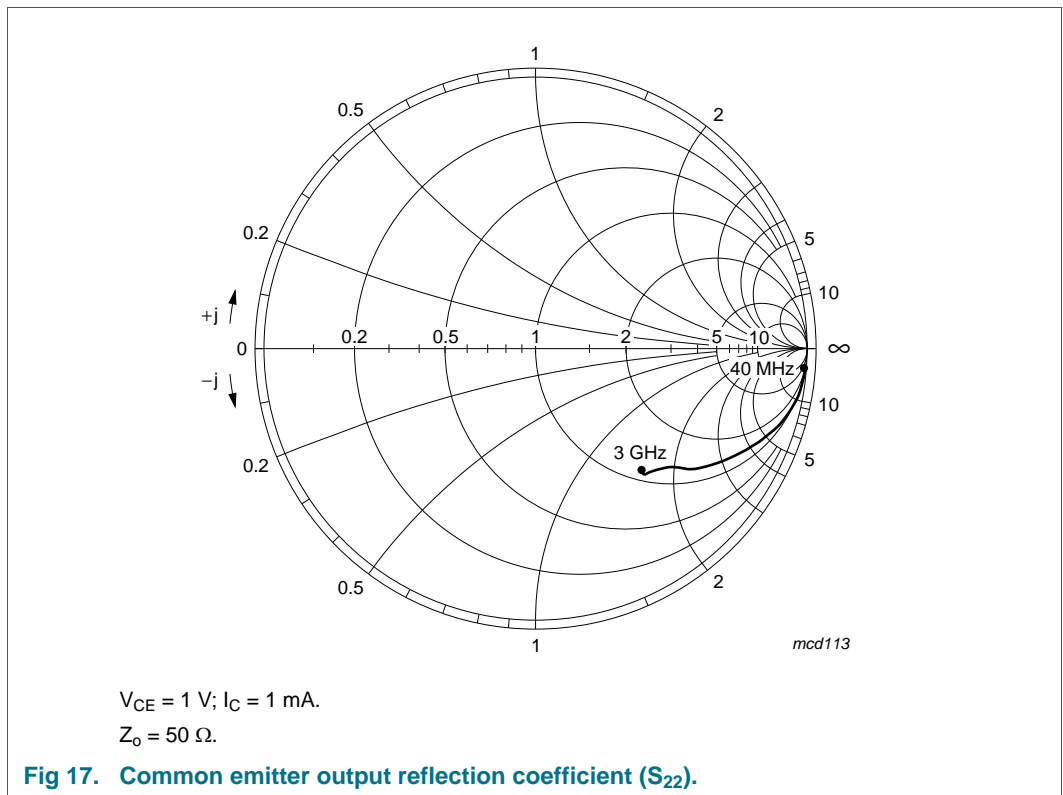
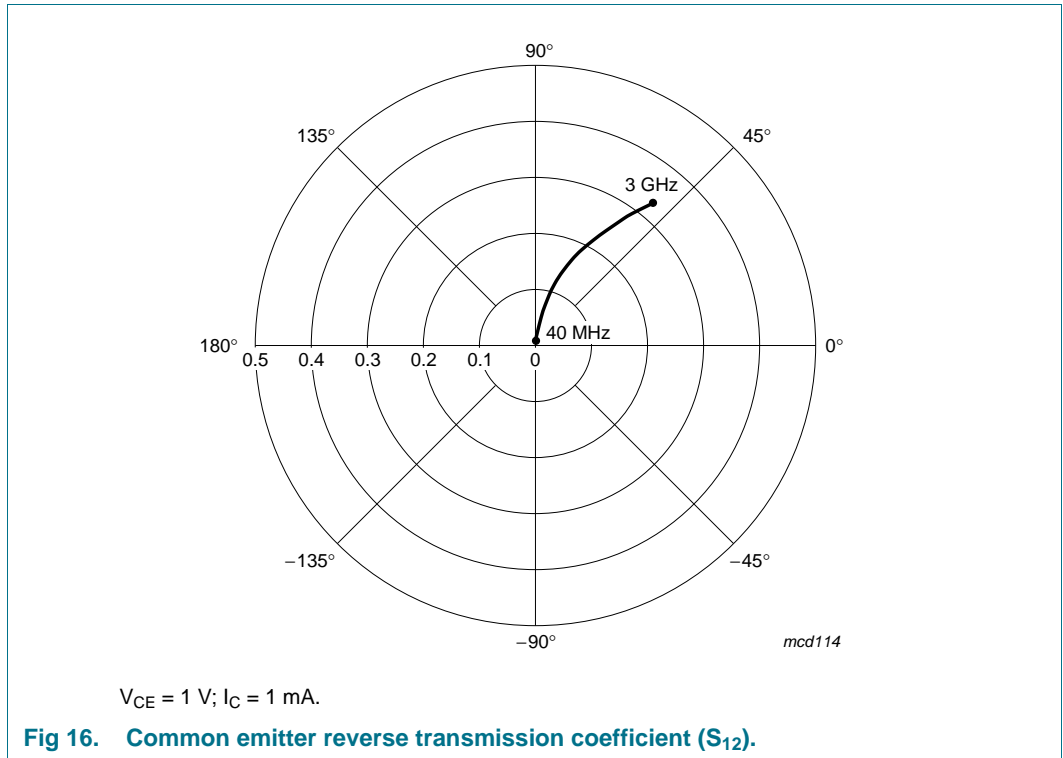


Table 10. Noise parameters

f (MHz)	V _{CE} (V)	I _C (mA)	F _{min} (dB)	Γ _{opt}		R _n /50
				(mag)	(ang)	
2000	1	1	2.4	0.72	26	1.7





8. Package outline

Plastic surface-mounted package; 3 leads

SOT23

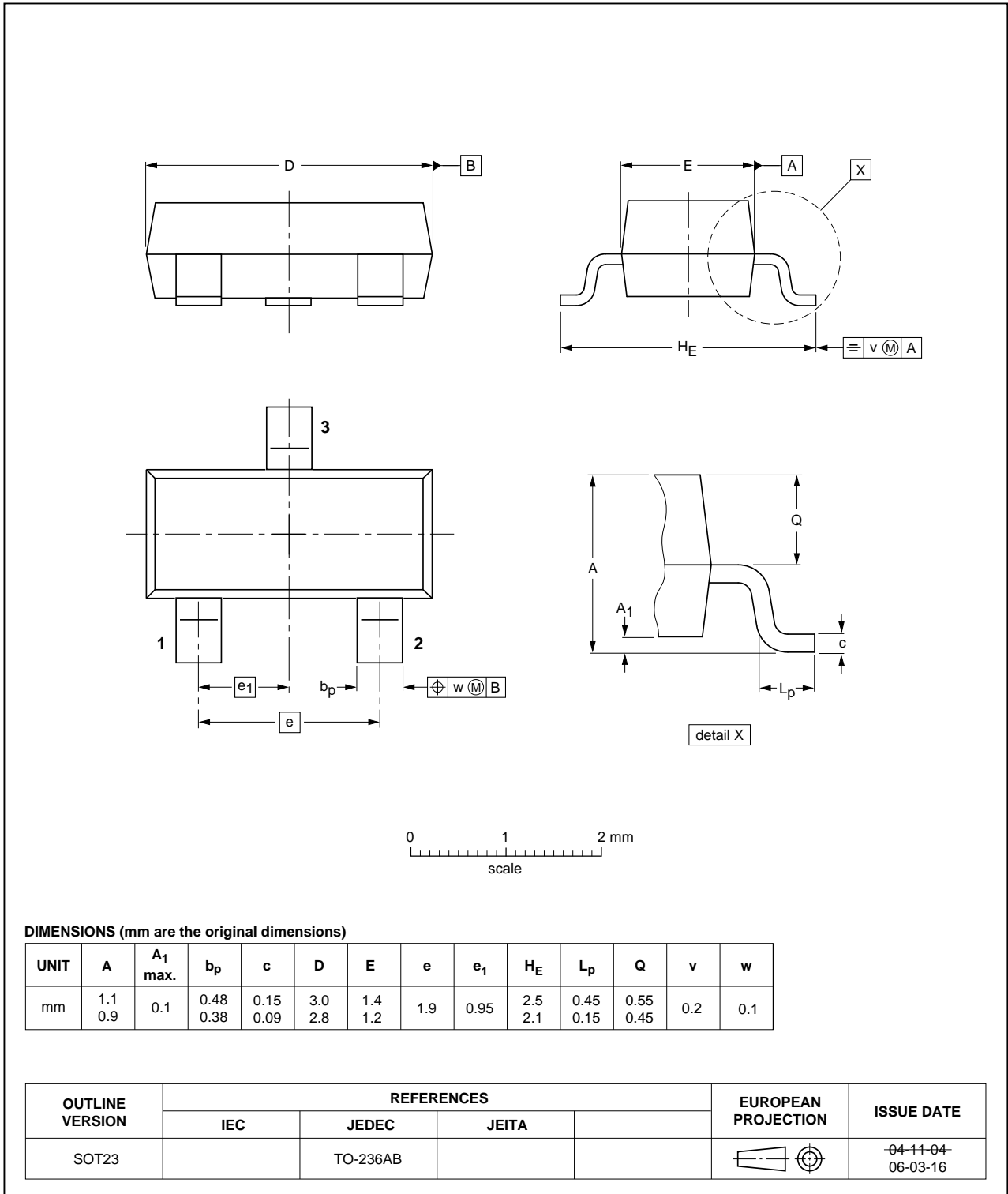


Fig 18. Package outline.

9. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BFT25A v.5	20110912	Product data sheet	-	BFT25A v.4
Modifications:		<ul style="list-style-type: none">• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.• Legal texts have been adapted to the new company name where appropriate.• Package outline drawings have been updated to the latest version.		
BFT25A v.4 (9397 750 13399)	20040706	Product data sheet	-	BFT25A_CNV v.3
BFT25A_CNV v.3	19971205	Product specification	-	-

10. Legal information

10.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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[2] The term 'short data sheet' is explained in section "Definitions".

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